Chapter 10

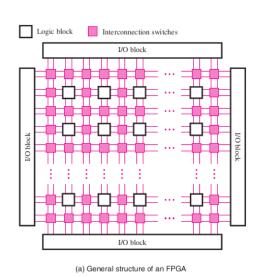
Analog details

Some of the material is out of the textbook. Additional resources include Appendix B of Brown and Vranesic book, "Fundamentals of digital logic."

10.1 Objectives

- 1. Describe how tri-state and open-collector outputs are different from totem-pole outputs
- 2. Compute noise margin of one device driving the same time

10.2 FPGA [3, Section B.6.5]



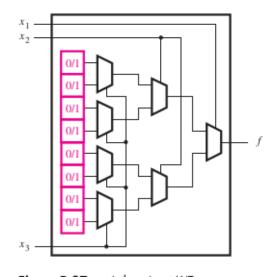


Figure B.37 A three-input LUT.

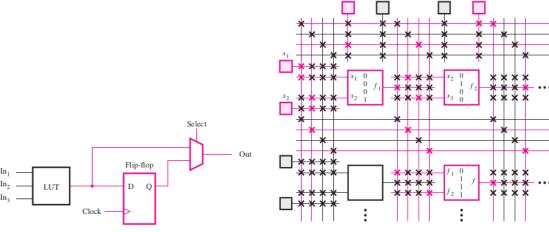


Figure B.38 Inclusion of a flip-flop in an FPGA logic element.

A section of a programmed FPGA.

Definition 10.1 (Random Access Memory (RAM)). Structure of a RAM is as follows:

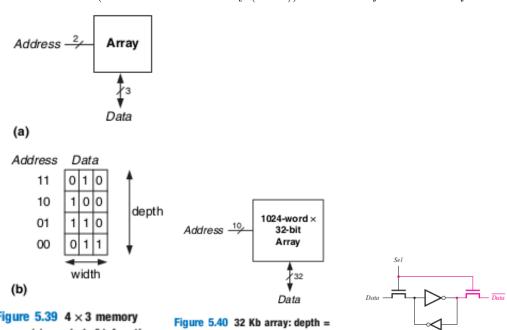


Figure 5.39 4 × 3 memory array: (a) symbol, (b) function

 $2^{10} = 1024$ words, width = 32 bits

An SRAM cell.

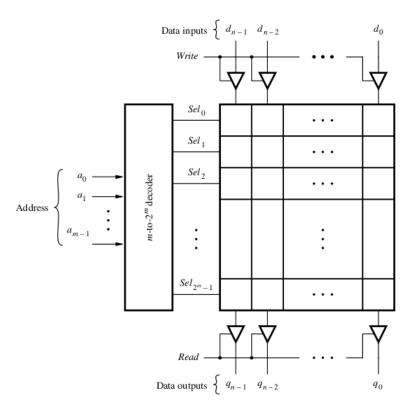


Figure B.66 A $2^m \times n$ SRAM block.

Definition 10.2 (Read Only Memory (ROM)). Structure of a ROM is as follows:

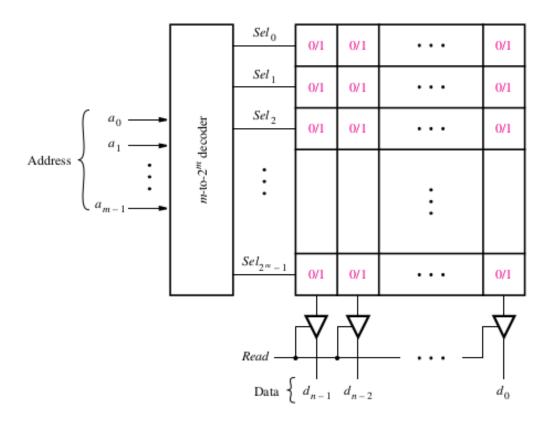
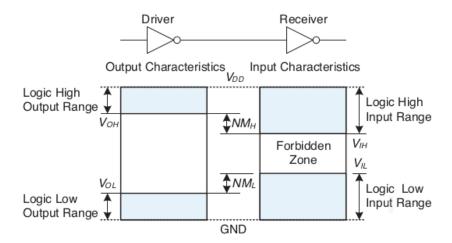


Figure B.72 A $2^m \times n$ read-only memory (ROM) block.

Example 10.1. Draw a Multiplexer using sum of products form.

10.3 Logic levels and Noise Margins



Definition 10.3 (Supply Voltage $(V_{DD}/V_{CC}/V_{SS})$). The highest DC voltage that drives a digital circuit. As chips have progressed to smaller transistors, V_{DD} has dropped from 5V to 1.2V or even lower to save power.

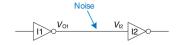
Definition 10.4 (Ground Voltage (V_{GND})). The lowest DC voltage that drives a digital circuit, typically ∂V .

Definition 10.5 (Input high (V_{IH}) and Input Low (V_{IL}) of a gate). V_{IH} is the voltage level, such that an input voltage to a gate between V_{DD} and V_{IH} is considered HIGH. Similarly, input voltage to a gate between V_{IL} and V_{GND} is considered LOW.

Definition 10.6 (Output high (V_{OH}) and Output low (V_{OL}) of gate). V_{OH} is the voltage level, such that an output voltage to a gate between V_{DD} and V_{OH} is considered HIGH. Similarly, output voltage to a gate between V_{OL} and V_{GND} is considered LOW.

Definition 10.7 (Positive logic and Negative logic). What we have considered so far is Positive logic where HIGH voltage is equated to Boolean logic TRUE or 1 and LOW is considered FALSE or 0. In negative logic these are reversed. Same physical circuit can represent different logical circuits in positive logic and negative logic.

Definition 10.8 (Noise margins $(NM_L \text{ and } NM_H)$ of a channel). The maximum amount of noise that can be added (or substracted) to a channel without exceeding the logic level specifications of a gate. $NM_L = V_{IL} - V_{OL}$ $NM_H = V_{OH} - V_{IH}$



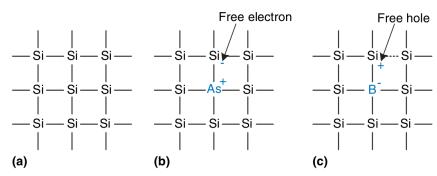
Example 10.2.

If $V_{DD} = 5V$, $V_{IL} = 1.35V$, $V_{IH} = 3.15V$, $V_{OL} = 0.33V$ and $V_{OH} = 3.84V$ for both the "inverters", then what are the low and high noise margins? Can the circuit tolerate 1V of noise at the channel?

10.4 Semiconductors and Doping

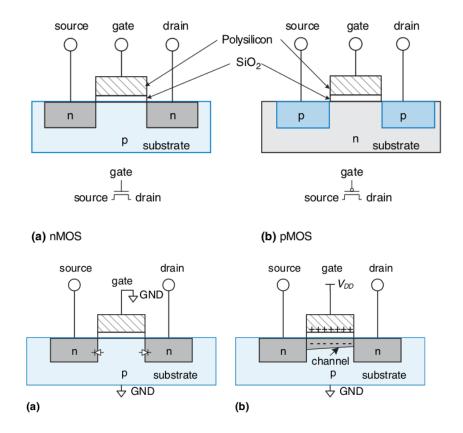
Not in syllabus but good to know

Elements recognized as metalloids V·T·E									
13		14 15		16	17				
2	В	С	N	0	F				
	Boron	Carbon	Nitrogen	Oxygen	Fluorine				
3	Al	Si	Р	S	Cl				
	Aluminium	Silicon	Phosphorus	Sulfur	Chlorine				
4	Ga	Ge	As	Se	Br				
-	Gallium	Germanium	Arsenic	Selenium	Bromine				
5	In	Sn	Sb	Te	I				
3	Indium	Tin	Antimony	Tellurium	Iodine				
6	TI	Pb	Bi	Ро	At				
ľ	Thallium	Lead	Bismuth	Polonium	Astatine				
Commonly recognized (86–99%): B, Si, Ge, As, Sb, Te Irregularly recognized (40–49%): Po, At Less commonly recognized (24%): Se Rarely recognized (8–10%): C, Al (All other elements cited in less than 6% of sources)									
Arbitrary metal-nonmetal dividing line: between									
Be and B, Al and Si, Ge and As, Sb and Te, Po and At									
_									

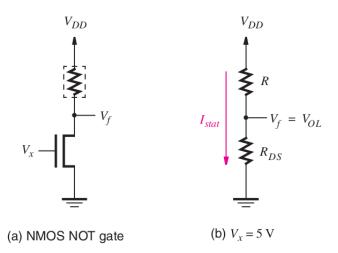


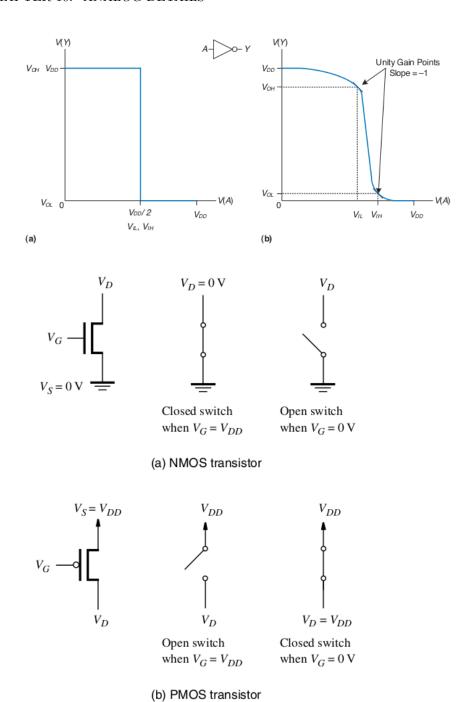
10.5 MOSFET: Metal Oxide Field Effect Transistors

Not in syllabus but good to know

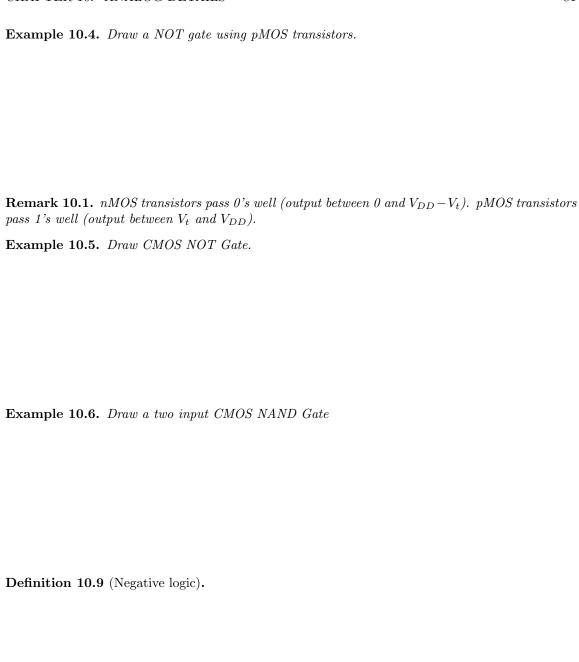


10.6 DC Transfer characteristic





Example 10.3. Draw a NOT gate using nMOS transistors.

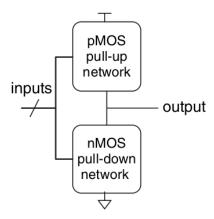


Example 10.8. Draw a three input NAND using CMOS.

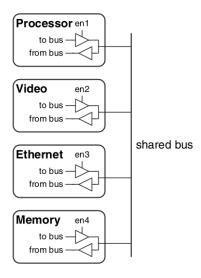
Example 10.7. Analyze the above circuit under negative logic.

Example 10.9. Draw a three input NOR using CMOS.

Example 10.10. Draw a two input AND gate using CMOS.



10.6.1 Gates with floating output



Definition 10.10 (Transmission gate). Draw a schematic of transmission gate and truth table for transmission gate. What is its commonly used symbol?

Definition 10.11 (Tristate buffer). What is tristate buffer? Draw it's symbol and truth table? Where is it used?

Example 10.11. Draw a Multiplexer using transmission gates.



10.7 Verilog truth tables

Table 11-11—Bitwise binary AND operator Table 11-12—Bitwise binary OR operator

&	0	1	x	z
0	0	0	0	0
1	0	1	х	x
x	0	x	x	x
z	0	x	x	x

I	0	1	х	z
0	0	1	х	х
1	1	1	1	1
x	х	1	х	х
z	x	1	х	x

Bibliography

- [1] Sarah L Harris and David Harris. *Digital design and computer architecture*. Morgan Kaufmann, 2022.
- [2] Randy Katz and Gaetano Barriello. Contemporary Logic Design. Prentice Hall, 2004.
- [3] Brown Stephen and Vranesic Zvonko. Fundamentals of digital Logic with Verilog design. McGraw Hill, 2022.